

S-Band Radar Miniature Power Amplifier

MPAG2735M30 is a miniaturized power amplifier which is internally matched to 50 ohms. It utilizes gallium nitride (GaN) high electron mobility transistor (HEMT) technology. This part is designed for S-Band radar applications operating over the 2.7 – 3.5 GHz instantaneous frequency band. Under 300us / 10% pulse conditions it supplies a minimum of 30 watts of peak output power with 11dB gain typically. Specified operation is with Class AB bias. When appropriately rated, it is operable under a wide range of pulse widths and duty factors. All devices are 100% screened for large signal RF parameters in a fixed tuned broadband matching circuit / test fixture. The use of external tuners is not allowed during screening. Not recommended for CW operation.



50 Ohm Matched

- Requires no external impedance matching circuitry

GaN on Silicon Carbide FET

- High Power Gain
- Excellent thermal stability
- Gold Metal

Depletion Mode Device

- Negative Gate Voltage to Bias
- Bias Sequencing Required
- See App Note to Prevent Damage

Gold Metal System

- Complete Gold System
- Gold Bond Wires
- Gold Package Metal
- Maximum Reliability

BeO Free Package

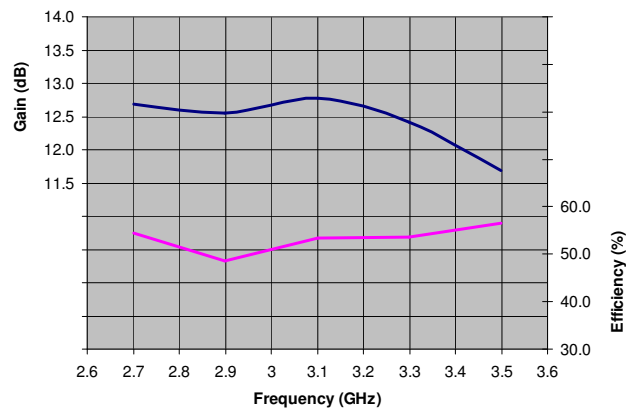
- Metal Based
- Epoxy Seal

High Power RF Test / Fixture

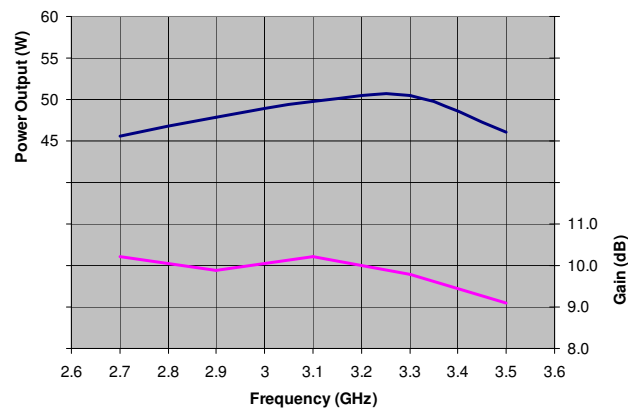
- Broadband
- Matched to 50 Ω (ohms)
- Long-term Correlation
- 100% Device RF Screening
- No External Tuning Allowed

SAMPLE RF DATA

Power Output = 30 Watts



Power Output = Saturated



MAXIMUM RATINGS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
BD	Drain-Source Breakdown Voltage	V_{DS-BK}	--	80	V	--
BD	Drain-Source Voltage	V_{DS}	--	40	V	--
BD	Gate-Source Voltage	V_{GS}	-10	0	V	--
BD	Storage Temperature Range	T_{STG}	-55	+150	°C	--
BD	Operating Junction Temperature Range	T_J	-55	+200	°C	--
BD	CW Power	P_{CW}	--	30	W	--
Note	Screen 'BD' = parameter qualified By Design.					

THERMAL CHARACTERISTICS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
BD	Thermal Resistance	$R_{TH(JC)}$	--	2.5	°C/W	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=25\pm5^\circ C, P_{OUT}=30W$
Note	Screen 'BD' = parameter qualified By Design.					

PROCESSING SPECIFICATIONS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
100%	DC Wafer Probe	--	--	--	--	Per Integra specification.
Q1	Wafer DC and RF Qualification	--	--	--	--	Per Integra specification.
LM	Wire Bond Strength	--	--	--	--	Line monitor per Integra specification.
100%	Pre-cap visual inspection	--	--	--	--	Per Integra specification
100%	Gross leak test	--	--	--	--	MIL-STD-750D, Method 1071.6, Test Condition C
Note	Screen 'Q1' = parameter is qualified by assembly and test of 3 pieces minimum per wafer.					
Note	Screen 'LM' = parameter is qualified by assembly line monitor.					

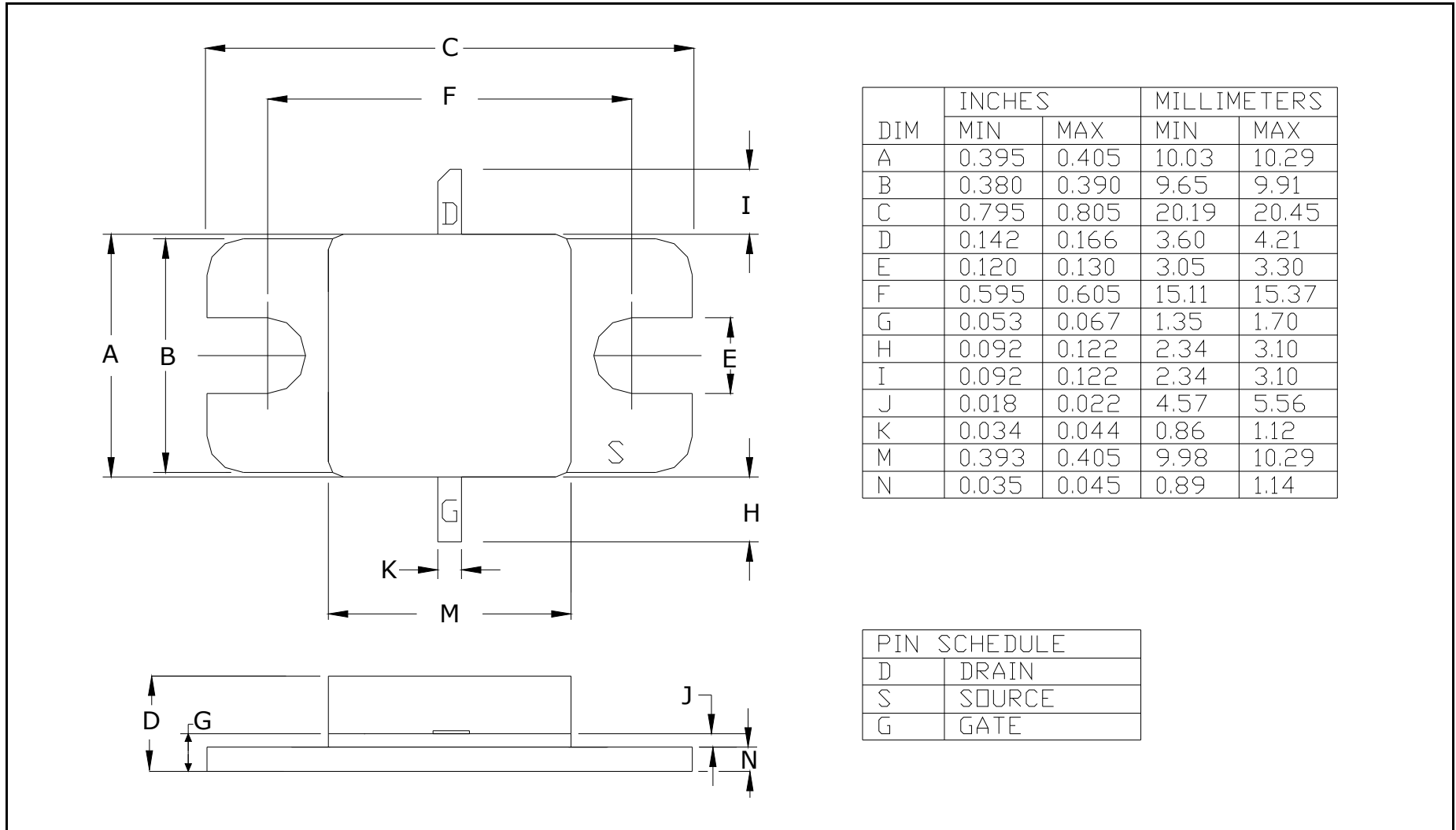
DC ELECTRICAL CHARACTERISTICS

Screen	Parameter	Symbol	Min	Typ	Max	Units	Test Conditions
100%	Drain Leakage Current	I_{D-OFF}	--	0.2*	--	mA	$V_{GS} = -8V, V_{DS} = 32V, T_F = 25\pm5^\circ C, *$ Typical Only.
100%	Gate Threshold Voltage	V_{GS-TH}	--	-3.5*	--	V	$V_{DS} = 32V, I_D = 40mA, T_F = 25\pm5^\circ C, *$ Typical Only.

RF ELECTRICAL CHARACTERISTICS

Screen	Parameter	Symbol	Min	Typ	Max	Units	Test Conditions
100%	Input Return Loss	IRL	-18	-10	-5	dB	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F1, F2, F3, F4, F5.$
100%	Power Gain	Gp	10.0	11.0	13.0	dB	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F1, F2, F3, F4, F5$
100%	Drain Efficiency	η_D	45	50	75	%	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F1, F2, F3, F4, F5$
100%	Pulse Amplitude Droop	D	-0.50	-0.10	0.30	dB	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F1, F2, F3, F4, F5$
100%	Delta Insertion Phase	DIP	-30	--	+30	DEG	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F5.$
100%	2:1 Load Mismatch Stability	VSWR-S	2:1		--	--	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F1, F2, F3, F4, F5$ Rotate 2:1 output VSWR through 360° phase. No oscillatory or pulse break-up characteristics allowed on detected output pulse. All non-harmonically related signals must be at least -65 dBc.
100%	3:1 Load Mismatch Tolerance	LMT	3:1		--	--	$V_{DD}=V1, I_{DQ}=I_{DQ1}, PW=PW1, DF=DF1, T_F=T_{F1}, P_{OUT}=P_{OUT1}, F=F1, F2, F3, F4, F5$ Rotate 3:1 output VSWR through 360° phase. Post test $P_O = \text{Pre test } P_{O\pm 1W}$
Note 1	$V1 = 32V; I_{DQ1} = 40mA; PW1 = 300\mu s; DF1 = 10\%; P_{OUT1} = 30W.$						
Note 2	Test Frequencies: F1 = 2.7 GHz, F2 = 2.9 GHz, F3 = 3.1 GHz, F4=3.3GHz, F5=3.5GHz						
Note 3	$T_{F1} = 30\pm 5^\circ C = \text{Device flange temperature.}$						
Note 4	Screen 'BD' = parameter qualified By Design.						

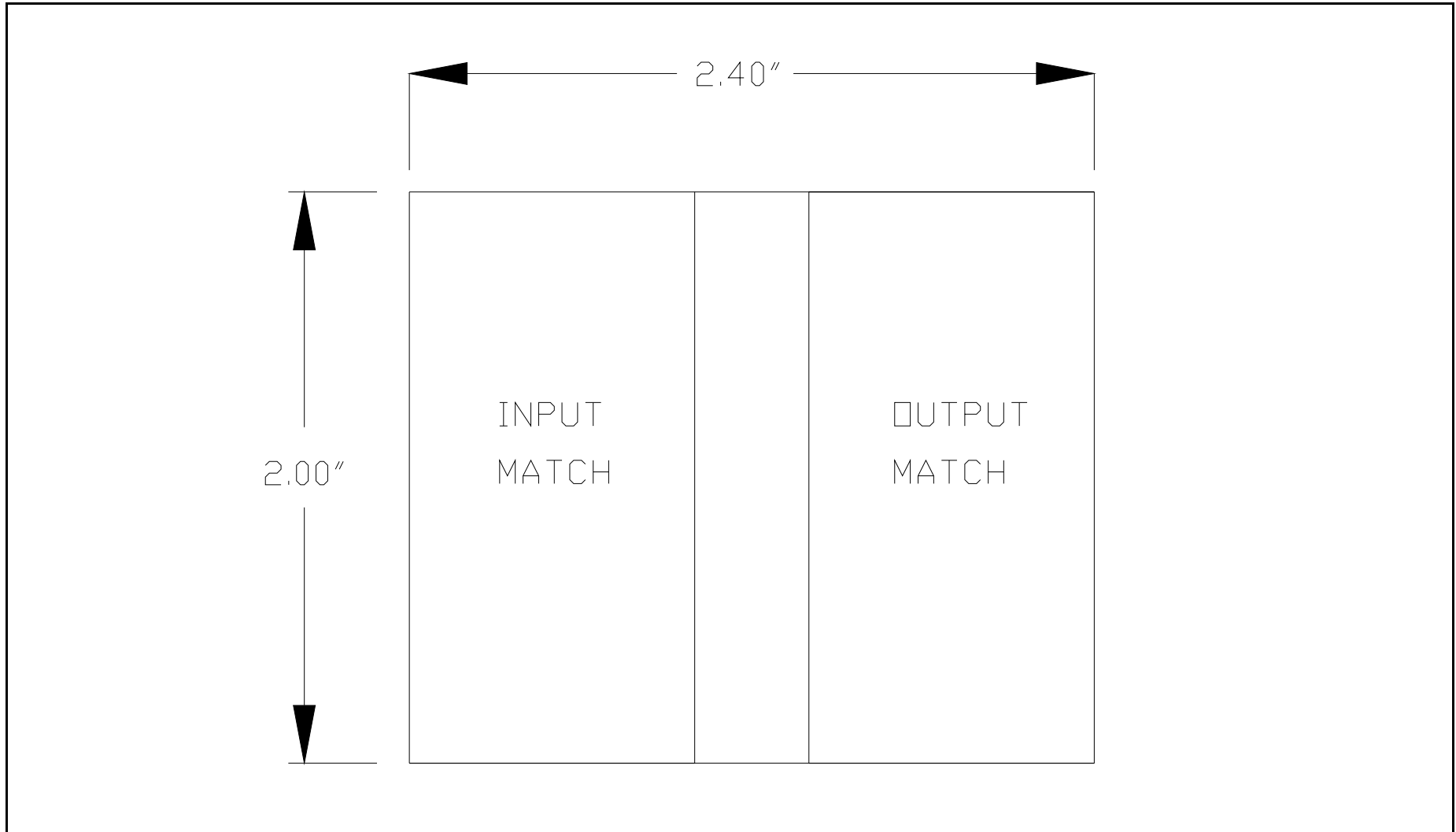
PACKAGE DIMENSIONAL OUTLINE DRAWING



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.395	0.405	10.03	10.29
B	0.380	0.390	9.65	9.91
C	0.795	0.805	20.19	20.45
D	0.142	0.166	3.60	4.21
E	0.120	0.130	3.05	3.30
F	0.595	0.605	15.11	15.37
G	0.053	0.067	1.35	1.70
H	0.092	0.122	2.34	3.10
I	0.092	0.122	2.34	3.10
J	0.018	0.022	4.57	5.56
K	0.034	0.044	0.86	1.12
M	0.393	0.405	9.98	10.29
N	0.035	0.045	0.89	1.14

PIN SCHEDULE	
D	DRAIN
S	SOURCE
G	GATE

RF TEST FIXTURE



CONTACT FACTORY FOR RF TEST FIXTURE CAD DRAWING WITH CIRCUIT DIMENSIONS

DEFINITIONS

Data Sheet Status	
Proposed Specification	This data sheet contains proposed specifications.
Preliminary Specification	This data sheet contains specifications based on preliminary measurements and data.
Product Specification	This data sheet contains final product specifications.
Maximum Ratings	
Stress above one or more of the maximum ratings may cause permanent damage to the device. These are maximum ratings only operation of the device at these or at any other conditions above those given in the characteristics sections of the specification is not implied. Exposure to maximum values for extended periods of time may affect device reliability.	

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